

Form PTO-1449  <b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b>  (Use several sheets if necessary)				ATTY. DOCKET NO. <b>3430-0200P</b>		APPLICATION NO. NEW <b>10/757521</b>		
				APPLICANT <b>Woong-Kwon KIM</b>				
				FILING DATE <b>January 15, 2003</b>		GROUP <b>Unassigned</b>		
U.S. PATENT DOCUMENTS								
EXAMINER INITIAL	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE	
a	US 5,994,721	A	1999-11-30	ZHONG et al				
	US 6,104,510	A		KASHIWAZAKI et al				
	US 6,104,459	A	2000-08-15	OIKE et al				
	US 5,724,107	A	1998-03-03	NISHIKAWA et al				
	US 6,211,928	B1	2001-04-03	OH et al				
	US 6,221,543	B1	2001-04-24	GUEHLER et al				
	US 5,994,721	A	1999-11-30	ZHONG et al				
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al				
	US 6,297,862	B1	2001-10-02	MURADE				
	US 6,166,786	A	2000-12-26	OHKUBO et al				
u	US 6,327,006	B1	2001-12-04	SATO et al				
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al				
	US 6,111,623	A	2000-08-29	SATO				
FOREIGN PATENT DOCUMENTS								
Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
							YES	NO
OTHER DOCUMENTS								
(Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.								
a	Pichon et al; "Low temperature unhydrogennated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136; 1997.							
EXAMINER				DATE CONSIDERED				
Hoan Nguyen				8/31/04				
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